NSN 5961-01-121-6332

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Inclosure Material:

Metal

Overall Length:

0.450 inches

Overall Diameter:

0.875 inches

End Application:

4920-01-094-8835 03640

Mounting Facility Quantity:

2

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

350.0 drain to source voltage

Current Rating Per Characteristic:

3.50 amperes drain current

Power Rating Per Characteristic:

75.0 watts total device dissipation

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Terminal Type And Quantity:

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0